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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Applicant

Yuanning Chen, et al.

Docket Number: TI-35022.2

Serial No.: 10/719,279

Art Unit: 2813

Filed: 11/21/03

Examiner: Jack S. J. Chen

For:

Use of Hafnium Silicon Oxynitride as the Cap Layer of the

Sidewall Spacer

CERTIFICATION OF FACSIMILE TRANSMISSION

I hereby certify that the following papers are being transmitted by facsimile to the U.S. Patent and Trademark Office on the date shown below:

FACSIMILE COVER SHEET

X FACSIMILE COVER SHEET NEW APPLICATION DECLARATION ASSIGNMENT FORMAL DRAWINGS INFORMAL DRAWINGS CONTINUATION APP'N DIVISIONAL APP'N		X AMENDMENT 116 (7 Pages) X EOT 1 month NOTICE OF APPEAL APPEAL (# Pages) ISSUE FEE & PUBLICATION FEE (1 Page) REPLY BRIEF (IN TRIPLICATE) (# Pages) ELECTION
NAME OF INVENTOR(S): Yuanning Chen, et al. TITLE OF INVENTION: Use of Hafnium Silicon Oxynitride as the Cap Layer of the Sidewall Spacer		RECEIPT DATE & SERIAL NO.: Serial No.: 10/719,279 Filing Date: 11/21/03
TI FILE NO: TI-35022.2 FAXED: 2-7-06 DUE: 12-18-04	DEPOSIT ACCT. NO.: 20-0668	

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> Texas Instruments Incorporated PO Box 655474, M/S 3999 Dallas, TX 75265-5474

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Examiner: Chen, Jack S J

Title: Use Of Hafnium Silicon Oxynitride As The Cap Layer Of The Sidewall

Spacer

AMENDMENT UNDER 37 C.F.R. §1.116

February 7, 2005

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450 CERTIFICATION OF FACSIMILE TRANSMISSION

I hereby certify that the above correspondence is being transmitted by facsimile to the U.S. Patent and Trademark Office at 703-872-9306 on the date shown below.

Karen Vertz

2-7-05

Dear Commissioner:

In response to the Office Action, dated 10/18/2004, in the above-identified patent application, please make the following amendments. They are respectfully submitted as a full and complete response to that Action. Charge any required fees to the deposit account of Texas Instruments Incorporated, Account No. 20-0668.